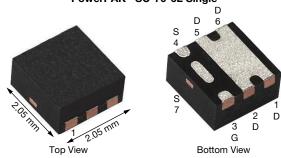


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Vishay Siliconix

# Automotive P-Channel 30 V (D-S) 175 °C MOSFET

### PowerPAK® SC-70-6L Single



Marking Code: QFXXXX

PRODUCT SUMMARY									
V <sub>DS</sub> (V)	-30								
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.020								
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.033								
I <sub>D</sub> (A)	-10								
Configuration	Single								
Package	PowerPAK SC-70								

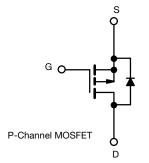
#### **FEATURES**

- TrenchFET® power MOSFET
- AEC-Q101 qualified d
- 100 % R<sub>g</sub> and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		$V_{DS}$	-30	V	
Gate-source voltage		V <sub>GS</sub>	± 20	V	
Continuous drain current	T <sub>C</sub> = 25 °C		-10		
Continuous drain current	T <sub>C</sub> = 125 °C	l <sub>D</sub>	-10		
Continuous source current (diode conduc	tion) <sup>a</sup>	Is	10	Α	
Pulsed drain current <sup>b</sup>	I <sub>DM</sub>	-40			
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	15		
Single pulse avalanche energy	L=0.11IIII	E <sub>AS</sub>	11.25	mJ	
Maximum power dissipation <sup>b</sup>	T <sub>C</sub> = 25 °C	Б	13.6	w	
waximum power dissipation -	T <sub>C</sub> = 125 °C	$P_{D}$	4.5		
Operating junction and storage temperatu	T <sub>J</sub> , T <sub>stq</sub>	-55 to +175	°C		

THERMAL RESISTANCE RATINGS									
PARAMETER		SYMBOL	LIMIT	UNIT					
Junction-to-ambient	PCB mount c	$R_{thJA}$	90	°C/W					
Junction-to-case (drain)		$R_{thJF}$	11	G/ <b>VV</b>					

#### Notes

- a. Package limited
- b. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. Parametric verification ongoing



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static	1				L	L	ı	
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0$ , $I_D = -250 \mu A$		-30	-	-	V	
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	V <sub>GS</sub> , I <sub>D</sub> = -250 μA	-1.5	-2	-2.5	V	
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V <sub>DS</sub> = -30 V	-	-	-1	μА	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = -30 V, T <sub>J</sub> = 125 °C	-	-	-50		
		$V_{GS} = 0 V$	V <sub>DS</sub> = -30 V, T <sub>J</sub> = 175 °C	-	-	-150		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = -10 V	$V_{DS} \ge 5 \text{ V}$	-8	-	-	Α	
		V <sub>GS</sub> = -10 V	I <sub>D</sub> = -5 A	-	0.016	0.020	9 0	
Drain aguras en eteta registance 3	Б	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -5 A, T <sub>J</sub> = 125 °C	-	-	0.029		
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -5 A, T <sub>J</sub> = 175 °C	-	-	0.035		
		V <sub>GS</sub> = -4.5 V	I <sub>D</sub> = -4 A	-	0.026	0.033		
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub>	-	17	-	S		
Dynamic <sup>b</sup>								
Input capacitance	C <sub>iss</sub>			-	1505	1880		
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -10 V, f = 1 MHz	-	205	260	pF	
Reverse transfer capacitance	C <sub>rss</sub>			-	181	227		
Total gate charge <sup>c</sup>	$Q_g$			-	26	33		
Gate-source charge <sup>c</sup>	$Q_{gs}$	V <sub>GS</sub> = -10 V	$V_{DS} = -15 \text{ V}, I_{D} = -8 \text{ A}$	-	4.2	-	nC	
Gate-drain charge c	$Q_{gd}$			-	4.7	-		
Gate resistance	$R_g$	f = 1 MHz		4.5	7.6	11.2	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	20	30		
Rise time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub> :	ı	18	27	ns		
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>	I <sub>D</sub> ≅ -2.5 A,	-	19	28			
Fall time <sup>c</sup>	t <sub>f</sub>	7	-	8	12			
Source-Drain Diode Ratings and Char	acteristics	•						
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	-40	Α	
Forward voltage	$V_{SD}$	I <sub>F</sub>	-	-0.8	-1.2	V		

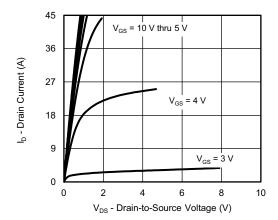
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

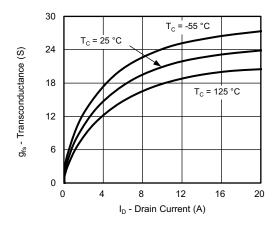
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



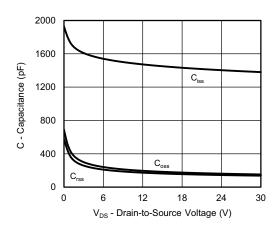
# **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



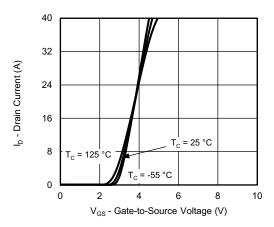
#### **Output Characteristics**



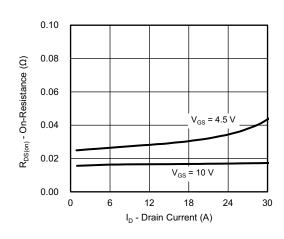
Transconductance



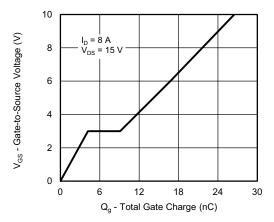
Capacitance



**Transfer Characteristics** 



On-Resistance vs. Drain Current

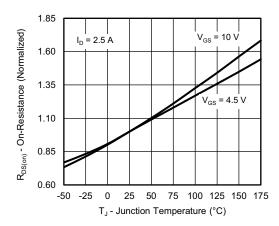


**Gate Charge** 

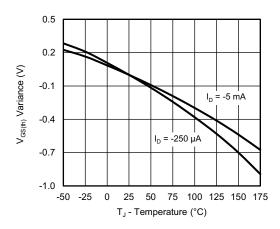


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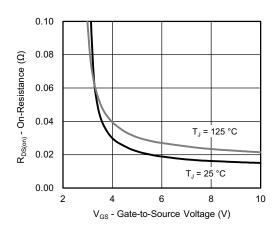
#### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



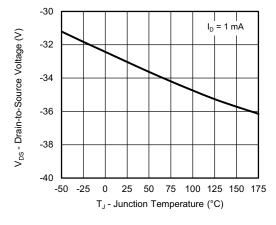
On-Resistance vs. Junction Temperature



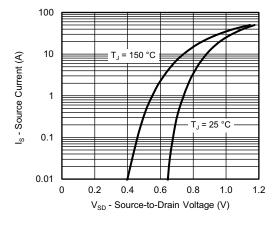
Threshold Voltage



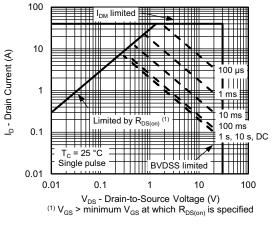
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature



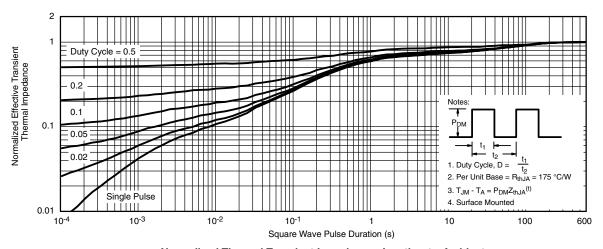
Source-Drain Diode Forward Voltage



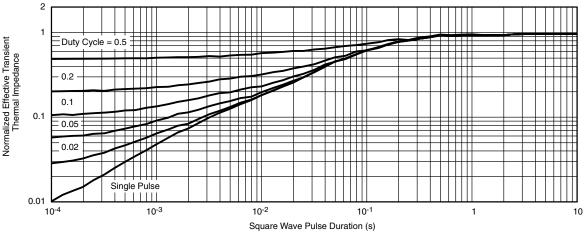
Safe Operating Area



## **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

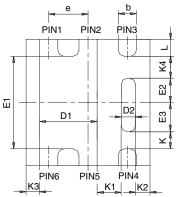
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg276242">www.vishay.com/ppg276242</a>.





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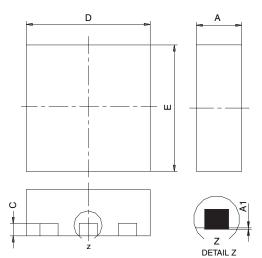
# PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
  Package outline exclusive of mold flash and metal burr
  Package outline inclusive of plating

	SINGLE PAD						DUAL PAD					
DIM	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
<b>A</b> 1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC			0.026 BSC	;	0.65 BSC			0.026 BSC		
K	0.275 TYP 0.011 TYP				0.275 TYP			0.011 TYP				
K1	0.400 TYP 0.016 TYP				0.320 TYP			0.013 TYP				
K2	0.240 TYP 0.009 TYP			0.252 TYP			0.010 TYP					
К3		0.225 TYP 0.009 TYP										
K4	0.355 TYP			0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
Т							0.05	0.10	0.15	0.002	0.004	0.006
=011 0 0		0 00 1										

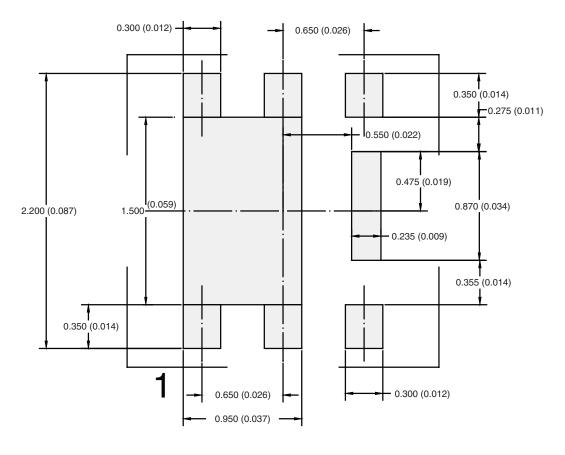
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DWG: 5934

Document Number: 73001 06-Aug-07



## RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

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ATTLICA ION NO



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